

2SC4869

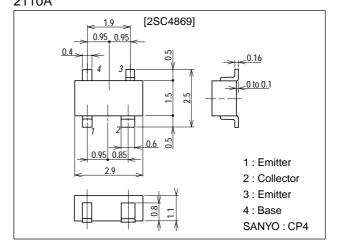
VHF to UHF Wide-Band Low-Noise Amplifier Applications

Features

Low noise: NF=1.2dB typ (f=1GHz).
High gain: |S21e|2=15dB typ (f=1GHz).
High cutoff frequency: f_T=9.0GHz typ.

Package Dimensions

unit:mm 2110A



Specifications

Absolute Maximum Ratings at Ta = 25°C

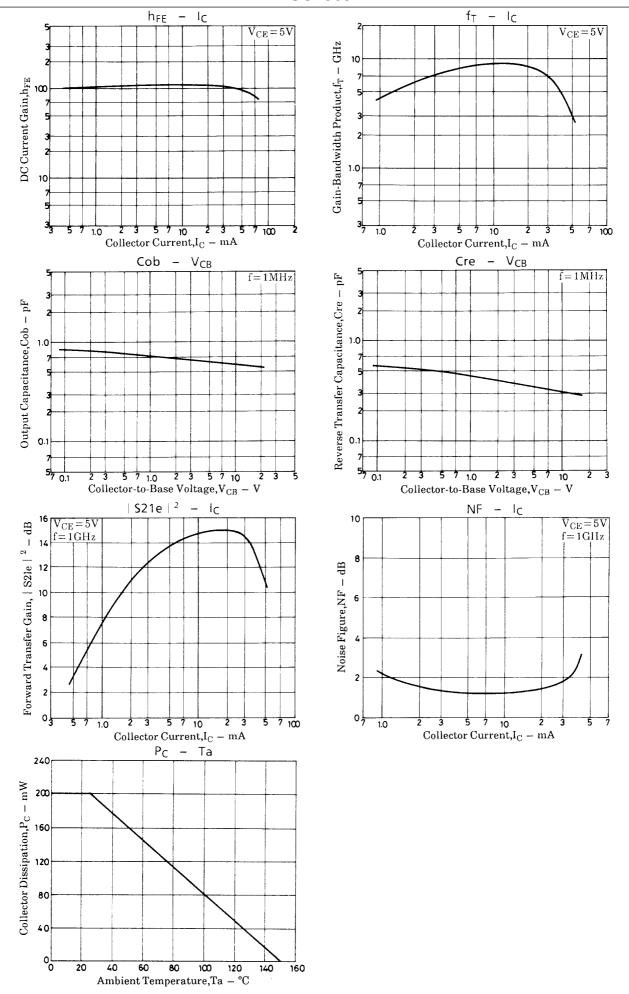
Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		16	V
Collector-to-Emitter Voltage	V _{CEO}		8	V
Emitter-to-Base Voltage	V _{EBO}		1.5	V
Collector Current	lс		50	mA
Collector Dissipation	PC		200	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol	Conditions	min	typ	max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} =10V, I _E =0			1.0	μA
Emitter Cutoff Current	I _{EBO}	V _{EB} =1V, I _C =0			10	μA
DC Current Gain	h _{FE}	V _{CE} =5V, I _C =15mA	60*		270*	
Gain-Bandwidth Product	f _T	V _{CE} =5V, I _C =15mA		9.0		GHz
Output Capacitance	Cob	V _{CB} =10V, f=1MHz		0.6	1.1	pF
Forward Transfer Gain	S21e ²	V _{CE} =5V, I _C =15mA, f=1GHz	12	15		dB
Noise Figure	NF	V _{CE} =5V, I _C =5mA, f=1GHz		1.2	2.5	dB

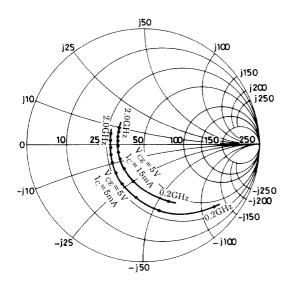
Marking: GN h_{FE} rank: 3, 4, 5

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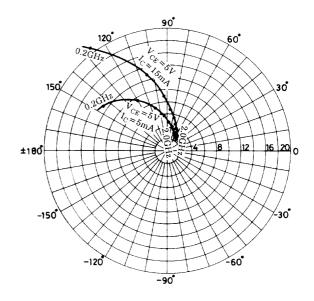


S parameter

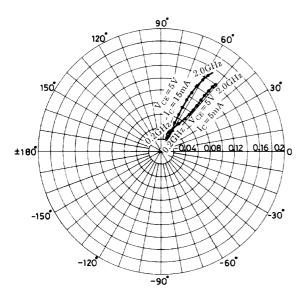
f = 200 to 2000 MHz (200 MHz step)



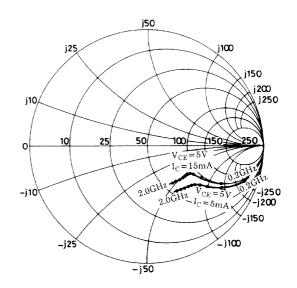
f = 200 to 2000 MHz (200 MHz step)



f = 200 to 2000 MHz (200 MHz step)



f = 200 to 2000 MHz (200 MHz step)



S parameter (Common emitter)

 V_{CE} =5V, I_C =5mA, Z_O =50 Ω

Freq (MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠ S ₂₂
200	0.782	-43.7	12.681	144.2	0.034	68.1	0.883	-19.9
400	0.591	-76.4	9.601	120.2	0.054	56.7	0.727	-29.9
600	0.467	-100.3	7.329	105.2	0.066	52.9	0.624	-34.5
800	0.393	-119.8	5.828	94.1	0.076	51.8	0.564	-37.4
1000	0.346	-135.3	4.831	85.6	0.090	51.8	0.532	-40.1
1200	0.322	-150.3	4.109	78.1	0.095	52.2	0.513	-42.5
1400	0.304	-163.6	3.585	71.7	0.106	52.2	0.499	-45.4
1600	0.299	-175.3	3.715	65.2	0.116	52.2	0.487	-49.0
1800	0.296	173.4	2.873	59.8	0.126	52.0	0.477	-52.7
2000	0.301	162.9	2.618	54.1	0.135	51.5	0.472	-57.0

$V_{CE}=5V, I_{C}=15mA, Z_{O}=50\Omega$

Freq (MHz)	S ₁₁	∠S ₁₁	S ₂₁	∠S ₂₁	S ₁₂	∠S ₁₂	S ₂₂	∠S ₂₂
200	0.525	-69.3	20.888	126.3	0.027	64.4	0.710	-28.0
400	0.347	-106.8	12.787	104.6	0.040	62.3	0.540	-32.0
600	0.281	-131.5	8.978	93.2	0.053	63.6	0.472	-32.8
800	0.251	-150.6	6.897	85.1	0.067	64.2	0.442	-34.3
1000	0.240	-164.7	5.584	78.6	0.080	64.0	0.428	-37.1
1200	0.235	-177.5	4.715	72.6	0.094	63.8	0.421	-39.6
1400	0.237	172.0	4.090	67.2	0.108	62.7	0.414	-42.9
1600	0.242	163.7	3.615	62.0	0.122	61.4	0.406	-47.1
1800	0.251	154.1	3.240	57.2	0.135	59.9	0.400	-51.3
2000	0.264	145.5	2.943	52.3	0.147	58.0	0.398	-56.0

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